

## **GBU10A thru GBU10G**

# Single Phase Glass Passivated Silicon Bridge Rectifier

 $V_{RRM} = 50 \text{ V} - 400 \text{ V}$  $I_{O} = 10 \text{ A}$ 

#### **Features**

- Epoxy Resin material compliant with 94V-0 standards of UL UL Material Flammability Provisions
- Compliant with UL Provisions, UL Code: E303851
- · Ideal for printed circuit boards
- · High surge overload rating
- High temperature soldering guaranteed: 260°C/ 10 seconds,
  9.5 mm lead length
- · Not ESD Sensitive

#### **Mechanical Data**

· Case: Epoxy resin body over passivated junctions

Weight: 4.60 g
 Mounting position:

• Mounting position: Any

#### **GBU Package**







#### Maximum ratings at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Conditions	GBU10A	GBU10B	GBU10D	GBU10G	Unit
Repetitive peak reverse voltage	$V_{RRM}$		50	100	200	400	V
RMS reverse voltage	$V_{RMS}$		35	70	140	280	V
DC blocking voltage	$V_{DC}$		50	100	200	400	V
Operating temperature	Tj		-40 to 150	-40 to 150	-40 to 150	-40 to 150	°C
Storage temperature	$T_{stg}$		-40 to 150	-40 to 150	-40 to 150	-40 to 150	°C

#### Electrical characteristics at T<sub>A</sub> = 25 °C, unless otherwise specified

Single phase, half sine wave, 50 Hz, resistive load

For capacitive load derate current by 20%

Parameter	Symbol	Conditions	GBU10A	GBU10B	GBU10D	GBU10G	Unit
Maximum forward rectified current	I <sub>O</sub>	T <sub>C</sub> = 100 °C	10 <sup>(1)</sup>	10 (1)	10 (1)	10 (1)	Α
		T <sub>A</sub> = 25 °C	3.5 <sup>(2)</sup>	3.5 <sup>(2)</sup>	3.5 <sup>(2)</sup>	3.5 <sup>(2)</sup>	
Peak forward surge current	I <sub>FSM</sub>	$t_p = 10 \text{ ms}, T_j = 25 ^{\circ}\text{C}$	225	225	225	225	Α
Maximum forward voltage drop	$V_{F}$	I <sub>F</sub> = 5 A	1.05	1.05	1.05	1.05	V
Maximum reverse current at rated DC blocking voltage	I <sub>R</sub>	T <sub>A</sub> = 25 °C	5	5	5	5	μA
		$T_A = 125  ^{\circ}C$	500	500	500	500	
Insulation strength (lead wire to case)	$V_{dis}$	AC voltage: 1 min leakage current<1mA	2.5	2.5	2.5	2.5	kV
Rating for fusing at $T_j = 25 \text{ C}$	l <sup>2</sup> t	1ms < t <sub>p</sub> < 10 ms	80	80	80	80	A <sup>2</sup> s
Typical thermal resistance	$R_{\Theta JA}$		23 (2)	23 (2)	23 (2)	23 (2)	°C/W
	$R_{\text{oJC}}$		5.0 <sup>(1)</sup>	5.0 <sup>(1)</sup>	5.0 (1)	5.0 <sup>(1)</sup>	
Mounting Torque	М	0.8 (0.5 N.m is recommended)					

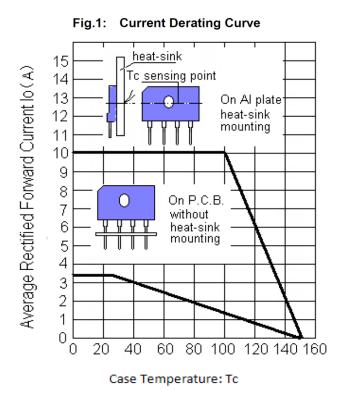
<sup>&</sup>lt;sup>1</sup> - Device mounted on 65 mm x 35 mm x 1.5 mm heatsink

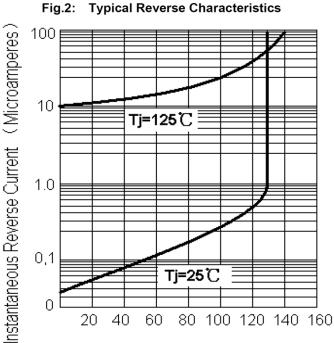
<sup>&</sup>lt;sup>2</sup> - Device mounted on PCB without heatsink

<sup>&</sup>lt;sup>3</sup> - Recommended mounted position is to bolt down device on a heatsink with silicon thermal compond for maximum heat transfer using M3 screw.



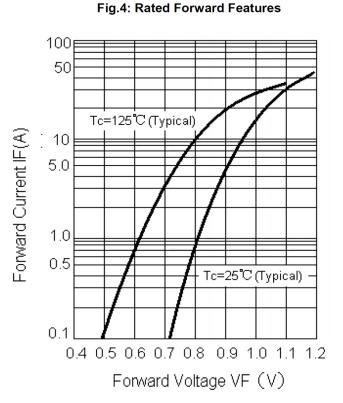






Percentage of Max. rated reverse voltage (VB%)

Fig.3: Max. Surge Current 300 270 Peak Surge Forward Current IFSM(A) 240 ms 10ms 1 cycle 10ms 210 non-repetitive sine wave 180 150 120 90 60 30 0 10 20 100 Number of Cycles at 50 Hz(cycles)

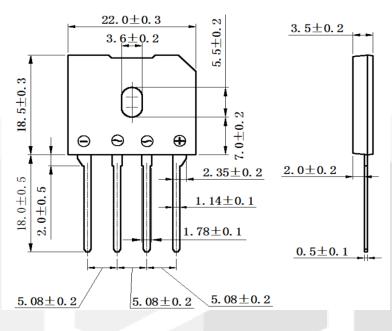




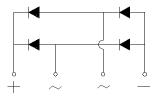
### Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.

#### **GBU**



Dimensions in millimeters



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